Three quadrant triacs

## GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a plastic envelope suitable for surface mounting intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DRM }}$ | BTA212B- <br> BTA212B- <br> BTA212B- <br> Repetitive peak off-state | $\begin{aligned} & \text { 600D } \\ & \text { 600E } \\ & \text { 600F } \\ & 600 \end{aligned}$ | 800E <br> 800F <br> 800 |  |
| $\begin{aligned} & \mathrm{I}_{\mathrm{T}(\text { RMS })} \\ & \mathrm{T}_{\mathrm{SSM}} \end{aligned}$ | RMS on-state current <br> Non-repetitive peak on-state current | $\begin{aligned} & 12 \\ & 95 \end{aligned}$ | $\begin{aligned} & 12 \\ & 95 \end{aligned}$ | $\begin{gathered} \text { A } \\ \text { A } \end{gathered}$ |

PINNING - SOT404

| PIN | DESCRIPTION |
| :---: | :--- |
|  | main terminal 1 |
| 2 | main terminal 2 |
| 3 | gate |
| mb | main terminal 2 |

PIN CONFIGURATION


## SYMBOL



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).


[^0]THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\mathrm{th} j-m b}$ | Thermal resistance | full cycle | - | - | 1.5 | $\mathrm{~K} / \mathrm{W}$ |
| $\mathrm{R}_{\mathrm{th} j-a}$ | junction to mounting base <br> junctal resistance <br> junction to ambient | half cycle <br> in free air | - | - | 2.0 | K/W |

## STATIC CHARACTERISTICS

$\mathrm{T}_{\mathrm{i}}=25^{\circ} \mathrm{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $I_{G T}$ | Gate trigger current ${ }^{2}$ | BTA212B- |  | ...D | ...D | ...E | $\ldots \mathrm{F}$ |  |
|  |  | $\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{\mathrm{T}}=0.1 \mathrm{~A}$ |  |  |  |  |  |  |
|  |  | $\mathrm{T} 2+\mathrm{G}+$ | - | 1.0 | 5 | 10 | 25 | mA |
|  |  | T2+ G- | - | 2.2 | 5 | 10 | 25 | mA |
| $\mathrm{I}_{\mathrm{L}}$ | Latching current | T2- G- | - | 3.3 | 5 | 10 | 25 | mA |
|  |  | $\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{\mathrm{GT}}=0.1 \mathrm{~A}$ |  |  |  |  |  |  |
|  |  | T2+ G+ | - | 6 | 15 | 25 | 30 | mA |
|  |  | T2+ G- | - | 6 | 25 | 30 | 40 | mA |
|  |  | T2- G- | - | 9 | 25 | 30 | 40 | mA |
| $\mathrm{I}_{\mathrm{H}}$ | Holding current | $\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{\mathrm{GT}}=0.1 \mathrm{~A}$ | - | 3.8 | 15 | 25 | 30 | mA |
|  |  |  | ...D, E, F |  |  |  |  |  |
| $\begin{aligned} & V_{T} \\ & V_{G T} \end{aligned}$ | On-state voltage Gate trigger voltage | $\begin{aligned} & \mathrm{I}_{T}=17 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{T}=0.1 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{D}}=400 \mathrm{~V} ; \mathrm{I}_{\mathrm{T}}=0.1 \mathrm{~A} ; \\ & \mathrm{T}_{\mathrm{j}}=125{ }^{\circ} \mathrm{C} \end{aligned}$ | - | 1.3 |  | 1.6 |  | V |
|  |  |  | - - | 0.7 |  | 1.5 |  | V |
|  |  |  | 0.25 | 0.4 |  |  |  | V |
| $\mathrm{I}_{\mathrm{D}}$ | Off-state leakage current | $\left\{\begin{array}{l} T_{\mathrm{j}}=125 \mathrm{C} \\ \mathrm{~V}_{\mathrm{D}}=\mathrm{V}_{\mathrm{DRM}(\max )} ; \\ \mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C} \end{array}\right.$ | - | 0.1 |  | 0.5 |  | mA |

## DYNAMIC CHARACTERISTICS

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. |  |  | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Critical rate of rise of off-state voltage | BTA212B- | ...D | ...E | ...F | ...D |  |  |
| $d V_{D} / \mathrm{dt}$ |  | $\mathrm{V}_{\text {DM }}=67 \% \mathrm{~V}_{\text {DRM(max }}$; $\mathrm{T}_{\mathrm{i}}=110^{\circ} \mathrm{C}$; exponential waveform; gate open | 20 | 60 | 70 | 30 | - | V/us |
| $\mathrm{dl}_{\text {com }} / \mathrm{dt}$ | Critical rate of change of commutating current |  | 1.8 | 3.5 | 5 | 3 | - | A/ms |
| $\mathrm{dl}_{\text {com }} / \mathrm{dt}$ | Critical rate of change of commutating current |  | 5 | 16 | 19 | 100 | - | A/ms |
|  |  |  | ...D, E, F |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{gt}}$ | Gate controlled turn-on time | $\begin{aligned} & \mathrm{I}_{\mathrm{TM}}=12 \mathrm{~A} ; \mathrm{V}_{\mathrm{D}}=\mathrm{V}_{\text {DRM(max }} ; \\ & \mathrm{I}_{\mathrm{G}}=0.1 \mathrm{~A} ; \mathrm{dl}_{\mathrm{G}} / \mathrm{dt}=5 \mathrm{~A} / \mu \mathrm{S} \end{aligned}$ | - | - | - | 2 | - | us |

2 Device does not trigger in the T2-, G+ quadrant.

Three quadrant triacs BTA212B series D, E and F guaranteed commutation


Fig.1. Maximum on-state dissipation, $P_{\text {tot, }}$ versus rms on-state current, $I_{T(\text { RMS })}$, where $\alpha=$ conduction angle.


Fig.2. Maximum permissible non-repetitive peak on-state current $I_{\text {TSM }}$, versus pulse width $t_{p}$, for sinusoidal currents, $t_{p} \leq 20 \mathrm{~ms}$.


Fig.3. Maximum permissible non-repetitive peak on-state current I ${ }_{\text {TSM }}$, versus number of cycles, for sinusoidal currents, $f=50 \mathrm{~Hz}$.


Fig.4. Maximum permissible rms current $I_{T(R M S)}$, versus mounting base temperature $T_{m b}$.


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(R M S)}$, versus surge duration, for sinusoidal currents, $f=50 \mathrm{~Hz} ; T_{m b} \leq 99^{\circ} \mathrm{C}$.


Fig.6. Normalised gate trigger voltage $V_{G T}\left(T_{j}\right) / V_{G T}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.

Three quadrant triacs guaranteed commutation


Fig.7. Normalised gate trigger current $I_{G T}\left(T_{j}\right) / I_{G T}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.


Fig.8. Normalised latching current $I_{L}\left(T_{j}\right) / I_{L}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.


Fig.9. Normalised holding current $I_{H}\left(T_{j}\right) / I_{H}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.


Fig.10. Typical and maximum on-state characteristic.
 pulse width $t_{p}$.


## Three quadrant triacs

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## MECHANICAL DATA



Fig.13. SOT404 : centre pin connected to mounting base.

## MOUNTING INSTRUCTIONS

Dimensions in mm


Fig.14. SOT404 : minimum pad sizes for surface mounting.

## Notes

1. Plastic meets UL94 V0 at 1/8".

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## DEFINITIONS

| Data sheet status |  |
| :--- | :--- |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one |
| or more of the limiting values may cause permanent damage to the device. These are stress ratings only and |  |
| operation of the device at these or at any other conditions above those given in the Characteristics sections of |  |
| this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |  |

## LIFE SUPPORT APPLICATIONS

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[^0]:    1 Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed $15 \mathrm{~A} / \mathrm{\mu s}$.

